



RoHS Compliance

AFC-Q200

This component is compliant with RoHS directive.

This component was always RoHS compliant from the first date of manufacture.

- Designed for 433.92 MHz Superheterodyne Receiver LOs
- · Very Low Series Resistance
- Quartz Stability
- · Surface-mount Ceramic Case

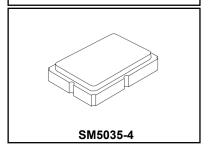
The RO3112A is a one-port surface-acoustic-wave (SAW) resonator packaged in a surface-mount ceramic case. It provides reliable, fundamental-mode quartz frequency stabilization of local oscillators operating at 433.42 MHz. The RO3112A is designed for 433.92 MHz superheterodyne receivers with a 500 kHz IF (Philips UAA3201T). Applications include remote-control and wireless security receivers operating in Europe under ETSI EN 300 220-2.

# **Absolute Maximum Ratings**

Rating	Value	Units
CW RF Power Dissipation (See Typical Test Circuit)	+0	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds / 5 cycles maximum)	260	°C

# **RO3112A**

# 433.42 MHz SAW Resonator



#### **Electrical Characteristics**

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency, +25 °C	Absolute Frequency	f <sub>C</sub>	2, 3, 4, 5	433.345		433.495	MHz
	Tolerance from 433.42 MHz	$\Delta f_{C}$				±75	kHz
Insertion Loss		IL	2, 5, 6		1.4	1.6	dB
Quality Factor	Unloaded Q	Q <sub>U</sub>	<del></del>		8000		
	50 Ω Loaded Q	Q <sub>L</sub>			1300		
Temperature Stability	Turnover Temperature	T <sub>O</sub>	6, 7, 8	10	25	40	°C
	Turnover Frequency	f <sub>O</sub>			f <sub>C</sub>		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	f <sub>A</sub>	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>			18.6	25	Ω
	Motional Inductance	L <sub>M</sub>	5, 7, 9		54.8		μH
	Motional Capacitance	C <sub>M</sub>	1		2.5		fF
	Transducer Static Capacitance	Co	5, 6, 9		3.7		pF
Test Fixture Shunt Inductance		L <sub>TEST</sub>	2, 7		36.8		nH
Lid Symbolization		658 // YYWWS					

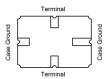
# CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. NOTES:

- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65 °C or less. Aging may exceed the specification for prolonged temperatures above +65 °C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
  The center frequency, f<sub>C</sub>, is measured at the minimum insertion loss point, with the reconstruction to 50 October 2012 (2012).
- The center frequency, f<sub>C</sub>, is measured at the minimum insertion loss point, IL<sub>MIN</sub>, with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L<sub>TEST</sub>, is tuned for parallel resonance with C<sub>O</sub> at f<sub>C</sub>. Typically, f<sub>OSCILLATOR</sub> or f<sub>TRANSMITTER</sub> is approximately equal to the resonator f<sub>C</sub>.
- One or more of the following United States patents apply: 4,454,488 and 4,616,197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment
- 5. Unless noted otherwise, case temperature  $T_C$  = +25 ± 2 °C.
- The design, manufacturing process, and specifications of this device are subject to change without notice.

- Derived mathematically from one or more of the following directly measured parameters: f<sub>C</sub>, IL, 3 dB bandwidth, f<sub>C</sub> versus T<sub>C</sub>, and C<sub>O</sub>.
  Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover)
- Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover) frequency, f<sub>O</sub>. The nominal frequency at any case temperature, T<sub>C</sub>, may be calculated from: f = f<sub>O</sub> [1 FTC (T<sub>O</sub> -T<sub>C</sub>)<sup>2</sup>]. Typically, oscillator T<sub>O</sub> is approximately equal to the specified resonator T<sub>O</sub>.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance  $C_O$  is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can be calculated as:  $C_P \approx C_O$  0.05 pF.
- 10. Packaged in 500PC Tape carrier.

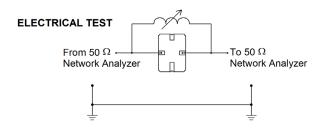
# **Electrical Connections**

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.

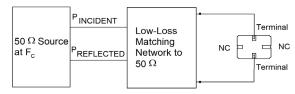


# **Typical Test Circuit**

The test circuit inductor,  $L_{TEST}$ , is tuned to resonate with the static capacitance,  $C_{O}$ , at  $F_{C}$ .



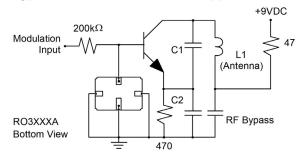
#### **POWER TEST**



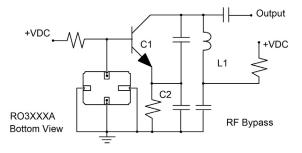
CW RF Power Dissipation = P INCIDENT P REFLECTED

# **Typical Application Circuits**

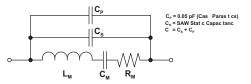
# **Typical Low-Power Transmitter Application**



# **Typical Local Oscillator Applications**

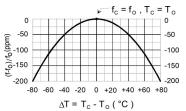


# **Equivalent RLC Model**

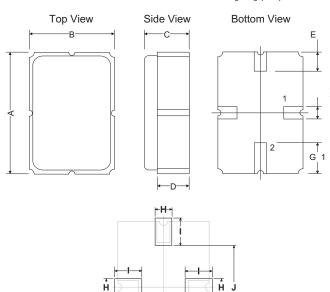


#### **Temperature Characteristics**

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



### Case



PCB Land Pattern Top View

Dimensions	Millimeters			Inches		
Difficusions	Min	Nom	Max	Min	Nom	Max
Α	4.87	5.00	5.13	0.191	0.196	0.201
В	3.37	3.50	3.63	0.132	0.137	0.142
С	1.45	1.53	1.60	0.057	0.060	0.062
D	1.35	1.43	1.50	0.040	0.057	0.059
E	0.67	0.80	0.93	0.026	0.031	0.036
F	0.37	0.50	0.63	0.014	0.019	0.024
G	1.07	1.20	1.33	0.042	0.047	0.052
Н	-	1.04	-	-	0.041	-
I	-	1.46	-	-	0.058	-
J	-	3.01	-	-	0.119	-
K	-	1.44	-	-	0.057	-
L	-	1.92	-	-	0.076	-